



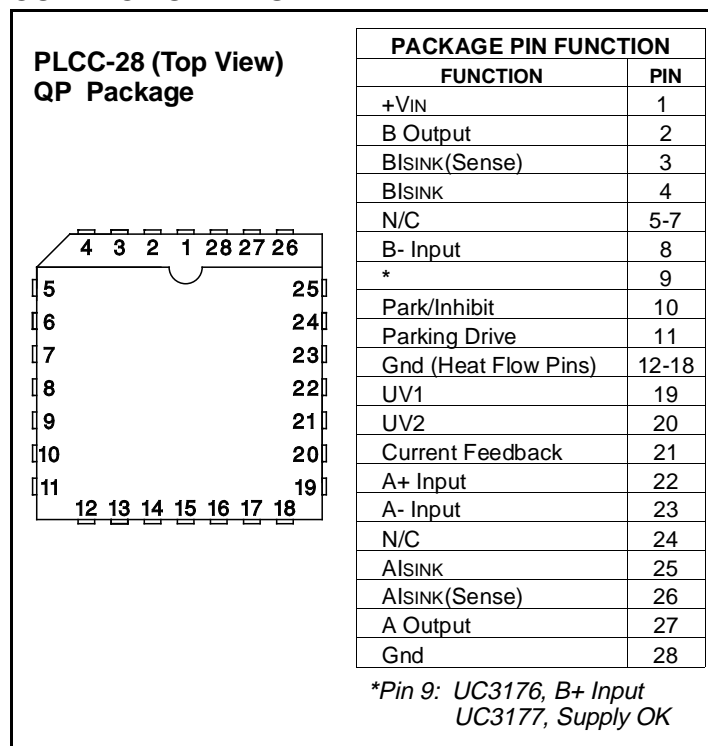
## ABSOLUTE MAXIMUM RATINGS (Note 1)

Input Supply voltage, (+VIN) . . . . . 40V  
Park/Inhibit, UV1 and UV2 inputs (zener clamped)  
Maximum forced voltage . . . . . -0.3V to 10V  
Maximum forced current. . . . .  $\pm 10\text{mA}$   
Other Input Voltages. . . . . -0.3V to +VIN  
ALSINK and BLSINK Voltages. . . . . -0.3V to 6V  
Open Collector Output Voltages. . . . . 40V  
A and B Output Currents (Continuous)  
Source . . . . . Internally Limited  
Sink. . . . . 2.5A  
Total Supply Current (Continuous). . . . . 4A  
Parking Drive Output Current (Continuous). . . . . 200mA  
Supply OK Output Current, UC3177 (Continuous) . . . 30mA  
Operating Junction Temperature . . . . . -55°C to +150°C  
Power Dissipation at TC = +75°C  
QP package. . . . . 4W  
Storage Temperature . . . . . -65°C to +150°C  
Note 1: Unless otherwise indicated, voltages are reference to ground and currents are positive into, negative out of, the specified terminals.

## THERMAL DATA

QP package:  
Thermal Resistance Junction to Leads,  $\theta_{JL}$  . . . . . 15°C/W  
Thermal Resistance Junction to Ambient,  $\theta_{JA}$  . . . . . 50°C/W

## CONNECTION DIAGRAM



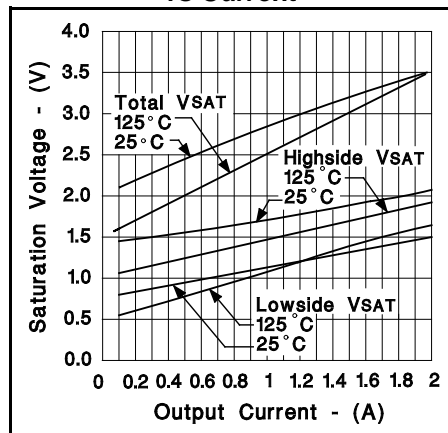
**ELECTRICAL CHARACTERISTICS:** Unless otherwise stated, specifications hold for TA = 0 to 70°C, +VIN = 12V, TA = TJ.

PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
<b>Input Supply</b>					
Supply Current	+VIN = 12V		18	25	mA
	+VIN = 35V		21	30	mA
UVOL Threshold	+VIN low to high		2.8	3.0	V
	Threshold Hysteresis		220	300	mV
<b>Power, Amplifier, A and B</b>					
Input Offset Voltage	VCM = 6V, VOUT = 6V			8	mV
Input Bias Current	VCM = 6V, Except A+ Input	-500	-100		nA
Input Bias Current at A+/Reference Input	(A+/Ref - BLSINK)/36kohms; TJ = 25°C	23	28	35	$\mu\text{A/V}$
Input Offset Current B Amp (UC3176 Only)	VCM = 6V			200	nA
CMRR	VCM = 1 to 33V, +VIN = 35V, VOUT = 6V	70	100		dB
PSRR	+VIN = 5 to 35V, VCM = 2.5V	70	100		dB
Large Signal Voltage Gain	VOUT = 3V, w/IOUT = 1A to VOUT = 9V, w/IOUT = -1A	1.5	4		V/mV
Thermal Feedback	+VIN = 20V, Pd = 20W at opposite output		25	200	$\mu\text{V/W}$
Saturation Voltage	IOUT = -2A, High Side, TJ = 25°		1.9		V
	CIOUT = 2A, Low Side, TJ = 25°C		1.6		V
	Total VSAT at 2A, TJ = 25°C		3.5	3.7	V
Unity Gain Bandwidth			1		MHz
Slew Rate			1		V/ $\mu\text{s}$
Differential IOUT Sense Error Current in Bridge Configuration	IOUT(A) = -IOUT(B), /IOUT/- /ALSINK - BLSINK/				
	IOUT $\leq 200\text{mA}$		3.0	6.0	mA
	IOUT $\leq 2\text{A}$		5.0	10	mA
High Side Current Limiting	=VIN - VOUT < 12V		-2.7	-2.0	A

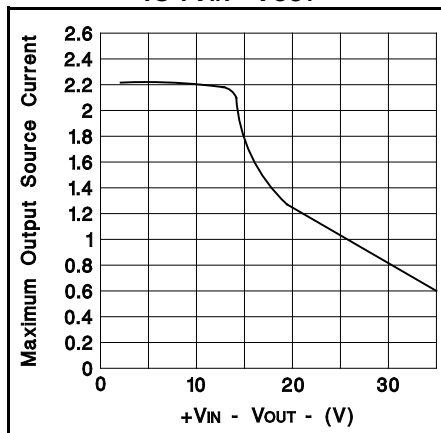
**ELECTRICAL CHARACTERISTICS:** Unless otherwise stated, specifications hold for  $T_A = 0$  to  $70^\circ\text{C}$ ,  $+V_{IN} = 12\text{V}$ ,  $T_A = T_J$ .

PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
<b>Current Sense Amplifier</b>					
Input Offset Voltage	$V_{CM} = 0\text{V}$ , A+/Ref at 6V Ref = 2V to 20V, $+V_{IN} = 35$ , change with Ref input voltage			3 600	mV $\mu\text{V/V}$
Thermal Gradient Sensitivity	$+V_{IN} = 20\text{V}$ , Ref = 10V Pd = 20W @ A or B output		5.0	75	$\mu\text{V/W}$
PSRR	Ref = 2.5V, $+V_{IN} = 5$ to 35V	70	100		dB
Gain	$ A_{SINK} - B_{SINK}  \leq 0.5\text{V}$	7.8	8	8.1	V/V
Slew Rate			2		V/ $\mu\text{S}$
3dB Bandwidth			1		MHz
Max Output Current	$I_{SOURCE} = +V_{IN} - V_{OUT} = 0.5\text{V}$	2.5	3.5		mA
Output Saturation Voltage	$I_{SOURCE} = 1.5\text{mA}$ , High Side		0.15	0.30	V
	$I_{SINK} = 5\text{mA}$ , Low Side		1.4	1.7	V
<b>Under-Voltage Comparator</b>					
Threshold Voltage	Low to High, other input at 5V	1.44	1.50	1.56	V
	Threshold Hysteresis	50	70	80	mV
Input Current	Input = 2V, other input at 5V	-2	-.05		$\mu\text{A}$
Supply OK $V_{SAT}$ (UC3177 Only)	$I_{OUT} = 5\text{mA}$			0.45	V
Supply OK Leakage (UC3177 Only)	$V_{OUT} = 35\text{V}$			5	$\mu\text{A}$
<b>Park/Inhibit</b>					
Park/Inhibit Thl'd		1.1	1.3	1.7	V
Park/Inhibit Input Current	At threshold		60	100	$\mu\text{A}$
Parking Drive Saturation Voltage	$I_{OUT} = 100\text{mA}$		0.3	0.7	V
Parking Drive Leakage	$V_{OUT} = 35\text{V}$			15	$\mu\text{A}$
<b>Thermal Shutdown</b>					
Shutdown Temperature			165		$^\circ\text{C}$

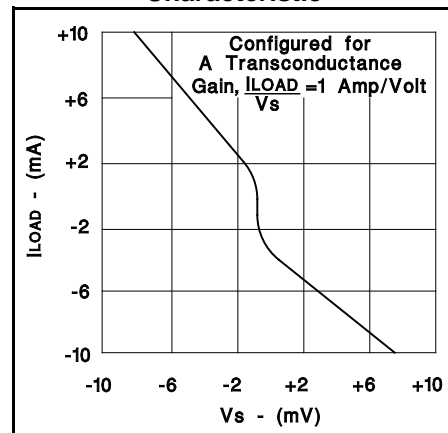
**Output Saturation Voltage vs Current**



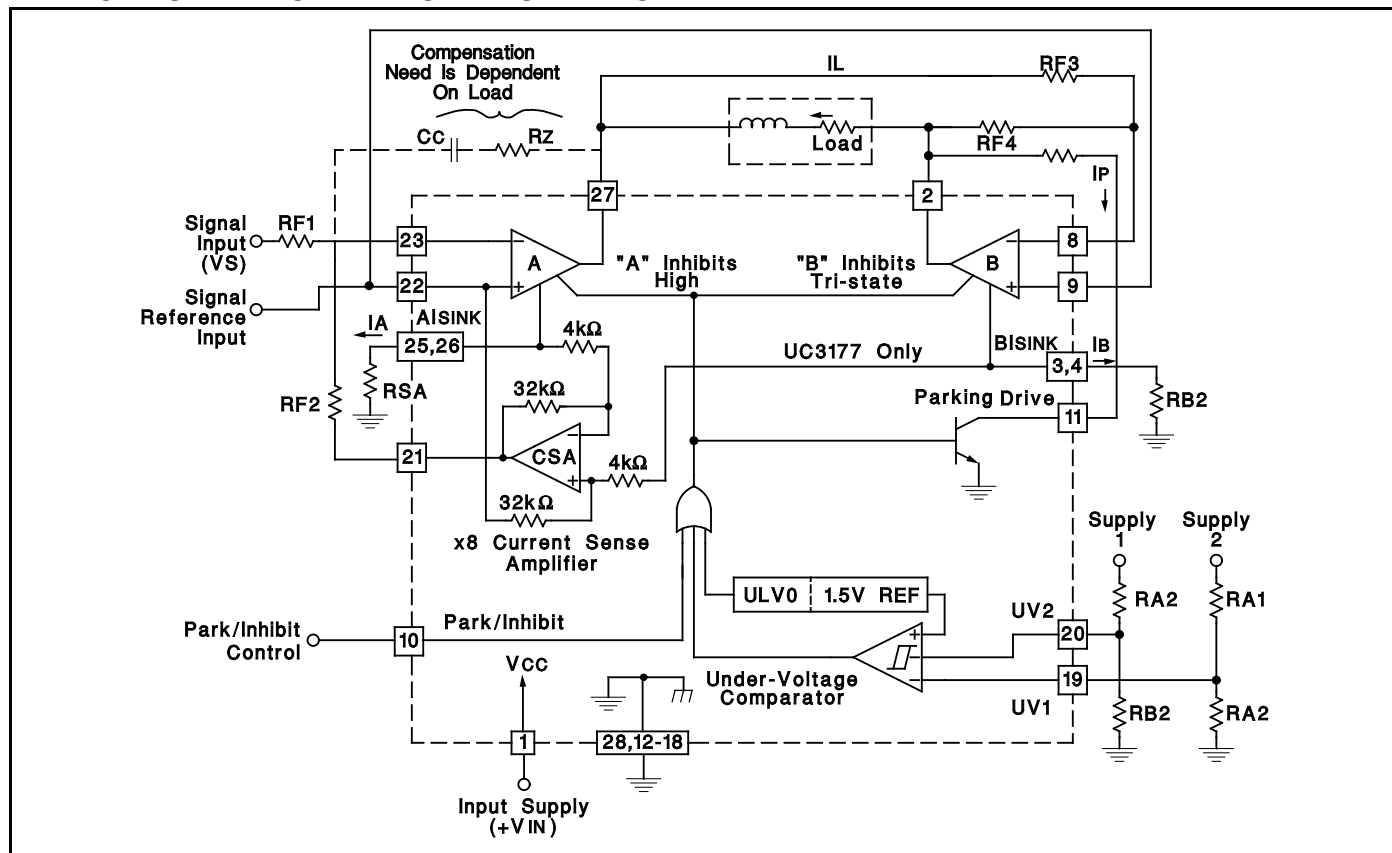
**Maximum Source Current vs  $+V_{IN} - V_{OUT}$**



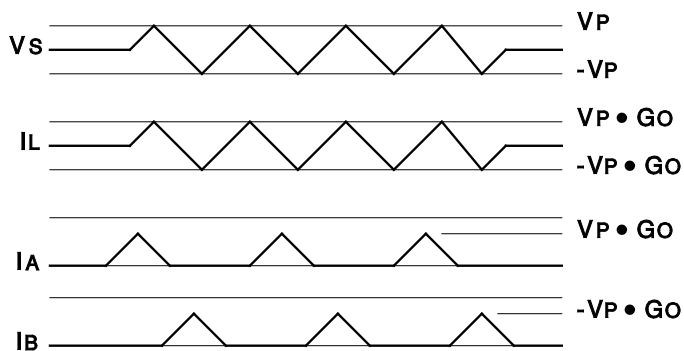
**Crossover Current Error Characteristic**



## APPLICATION AND OPERATION INFORMATION



### WAVEFORMS FOR ABOVE APPLICATION



### DESIGN EQUATIONS

$$\text{Transconductance (Go)} = \frac{I_L}{V_S} = \frac{R_{F2}}{R_{F1}} \times \left( \frac{1}{8R_S} \right)$$

with:  $R_{SA} = R_{SB}$  and  $R_{F3} = R_{F4}$

$$\text{Parking Current (IP)} = \frac{V_{IN} - 1.5}{R_P + R_L}$$

where:  $R_L$  = load resistance

Under-Voltage Thresholds, at Supplies  
 High to Low Threshold,  $(V_{LH}) = 1.425 (R_A + R_B)/R_B$   
 Low to High Threshold,  $(V_{HL}) = 1.5 (R_A + R_B)/R_B$

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